

# **Excellent Integrated System Limited**

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Fairchild Semiconductor FJV4107RMTF

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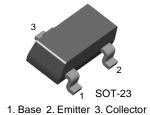




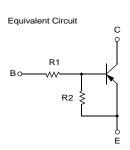
## **FJV4107R**

### Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R<sub>1</sub>=22K $\Omega$ , R<sub>2</sub>=47K $\Omega$ )
- Complement to FJV3107R







# **PNP Epitaxial Silicon Transistor**

# **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-10	V
I <sub>C</sub>	Collector Current	-100	mA
P <sub>C</sub>	Collector Power Dissipation	200	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C}$ = -10 $\mu$ A, $I_{E}$ =0	-50			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -100 \mu A, I_B = 0$	-50			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -40V, I <sub>E</sub> =0			-0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE}$ = -5V, $I_{C}$ = -5mA	68			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA			-0.3	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0 f=1MHz		5.5		pF
f <sub>T</sub>	Current Gain-Bandwidth Product	V <sub>CE</sub> = -10V, I <sub>C</sub> = -5mA		200		MHz
V <sub>I</sub> (off)	Input Off Voltage	$V_{CE}$ = -5V, $I_{C}$ = -100 $\mu$ A	-0.4			V
V <sub>I</sub> (on)	Input On Voltage	$V_{CE}$ = -0.3V, $I_{C}$ = -2mA			-2.5	V
R <sub>1</sub>	Input Resistor		15	22	29	ΚΩ
R <sub>1</sub> /R <sub>2</sub>	Resistor Ratio		0.42	0.47	0.52	

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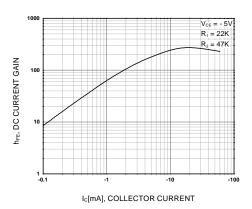


Figure 1. DC current Gain

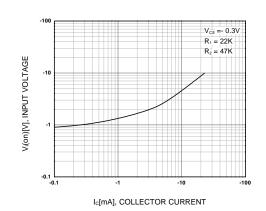


Figure 2. Input On Voltage

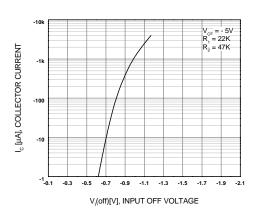


Figure 3. Input Off Voltage

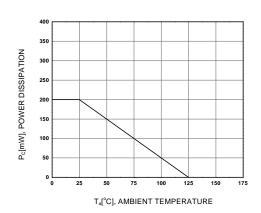
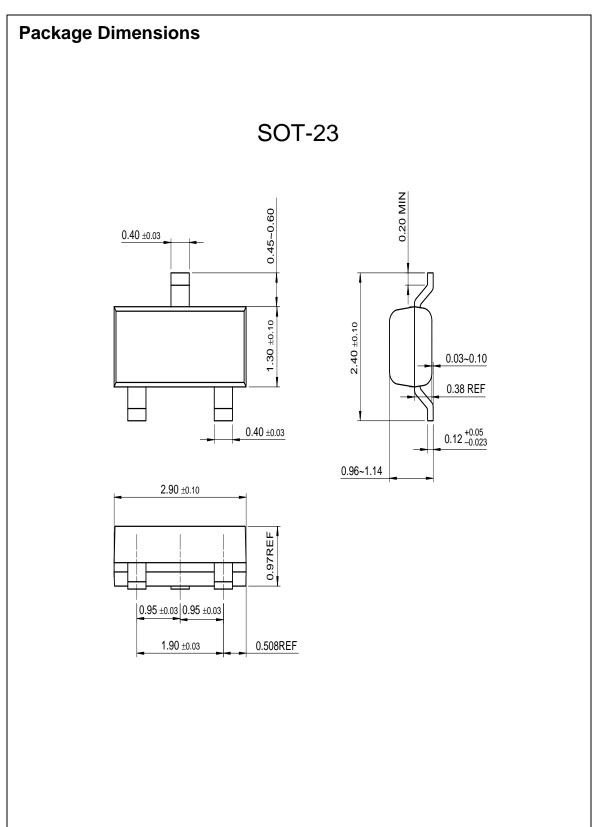


Figure 4. Power Derating

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**Dimensions in Millimeters** 

# **Distributor of Fairchild Semiconductor: Excellent Integrated System Limited**Datasheet of FJV4107RMTF - TRANS PREBIAS PNP 200MW SOT23-3

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